KS1060-Bidirectional thyristor

5800-6500 V_{DRM}

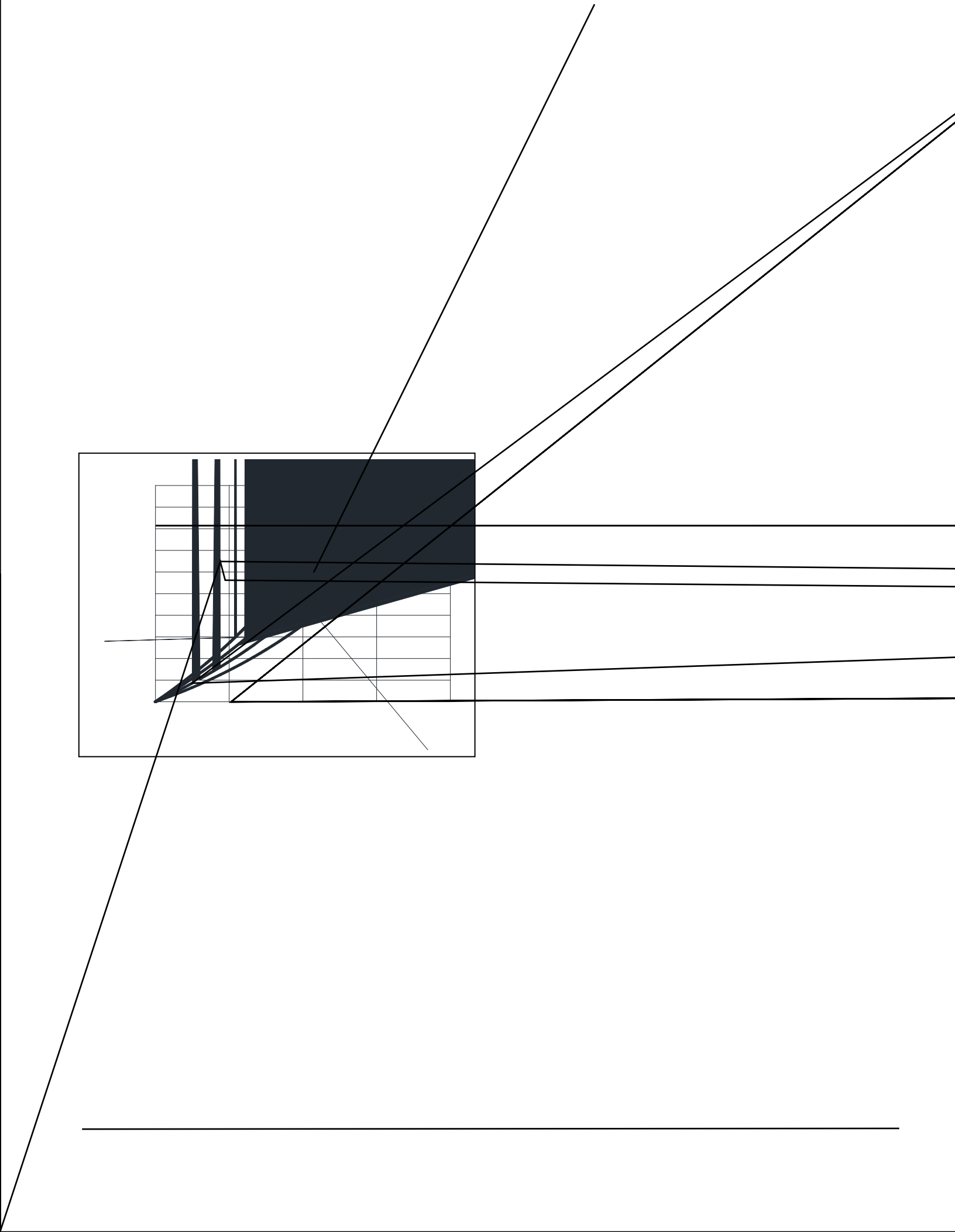
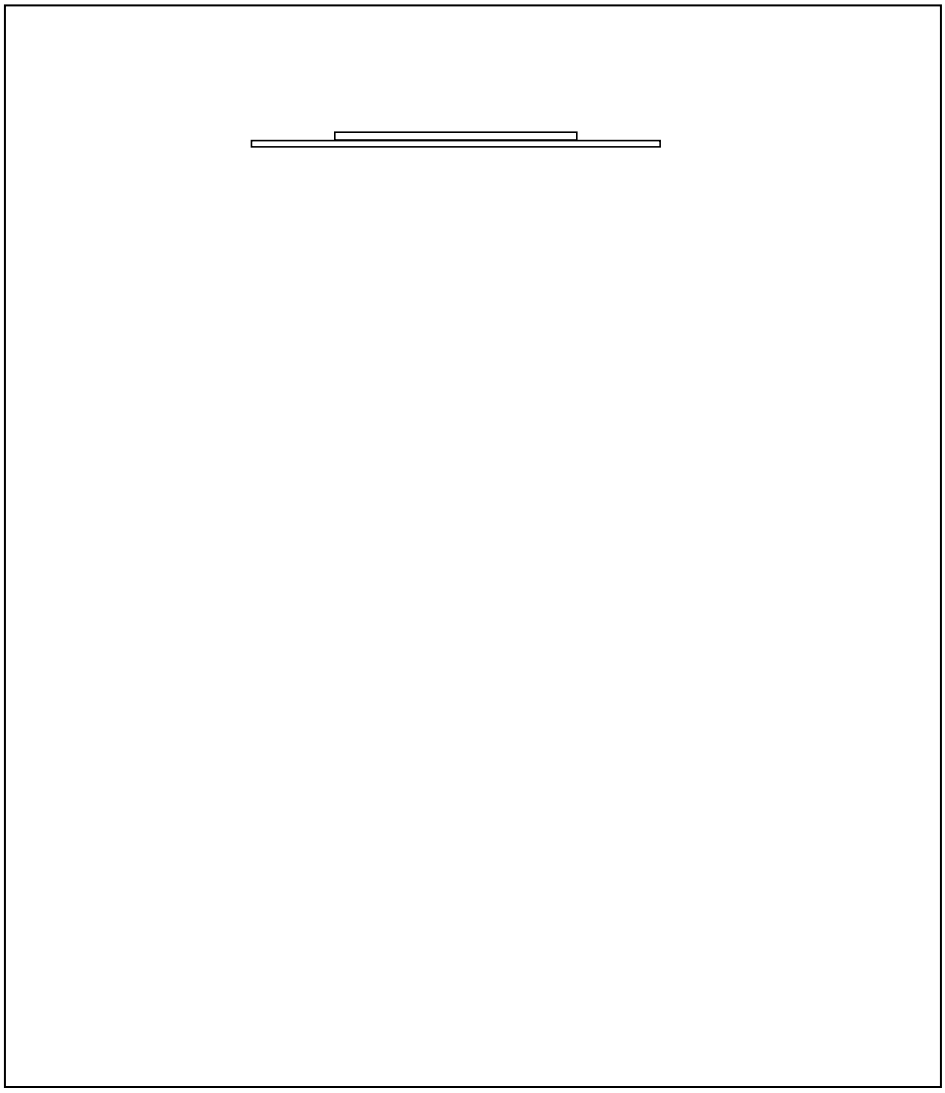
HIGH POWER BIDIRECTIONAL THYRISTOR

Features

. Amplifying Gate Configuration
. Two thyristors integrated into one wafer
. Blocking capability up to 6500 volts
. High power capability
. Full cold pressing encapsulation

ELECTRICAL CHARACTERISTICS AND RATINGS

Blocking-Off State

Gating

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions